

POWER DISCRETES

Description

Quick reference data

$$V_R = 50 - 600V$$

$$I_F = 4.5A$$

$$t_{rr} = 150 - 400ns$$

$$I_R = 1.0\mu A$$

Features

- ◆ Very low reverse recovery time
- ◆ Hermetically sealed in fused metal oxide
- ◆ Low switching losses
- ◆ Low forward voltage drop
- ◆ Soft, non-snap off, recovery characteristics

These products are qualified to MIL-PRF-19500/411. They can be supplied fully released as JAN, JANTX, and JANTXV versions.

Absolute Maximum Ratings

Electrical specifications @ $T_A = 25^\circ C$ unless otherwise specified.

	Symbol	1N5415 3SF05	1N5416 3SF1	1N5417 3SF2	1N5418 3SF4	1N5419 3SF5	1N5420 3SF6	Units
Working Reverse Voltage	V_{RWM}	50	100	200	400	500	600	V
Repetitive Reverse Voltage	V_{RRM}	50	100	200	400	500	600	V
Average Forward Current @ $55^\circ C$ in free air, lead length 0.375"	$I_{F(AV)}$	4.5						A
Repetitive Surge Current @ $55^\circ C$ in free air, lead length 0.375"	I_{FRM}	25						A
Non-Repetitive Surge Current ($t_p = 8.3ms$ @ V_R & T_{JMAX}) ($t_p = 8.3ms$, @ V_R & $25^\circ C$)	I_{FSM}	80 150						A
Storage Temperature Range	T_{STG}	-65 to +175						$^\circ C$

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Electrical Specifications

	Symbol	1N5415 3SF05	1N5416 3SF1	1N5417 3SF2	1N5418 3SF4	1N5419 3SF5	1N5420 3SF6	Units
Average Forward Current max. for sine wave, $T_A = 55^\circ\text{C}$	$I_{F(AV)}$	3.0						A
Average Forward Current max. ($T_L = 55^\circ\text{C}$; $L = 3/8"$) for sine wave for square wave	$I_{F(AV)}$ $I_{F(AV)}$	4.4 4.5						A
P_t for fusing ($t = 8.3\text{mS}$) max	P_t	90						A ² S
Forward Voltage Drop max. @ $I_F = 3.0\text{A}$, $T_J = 25^\circ\text{C}$	V_F	1.1						V
Reverse Current max. @ V_{RWM} , $T_J = 25^\circ\text{C}$ @ V_{RWM} , $T_J = 100^\circ\text{C}$	I_R I_R	1.0 20						μA
Reverse Recovery Time max. 0.5A I_F to 1.0A I_{RM} recovers to 0.25A $I_{RM(REC)}$	t_{rr}	150	150	150	150	250	400	nS
Junction Capacitance typ. @ $V_R = 4\text{V}$, $f = 1\text{MHz}$	C_j	550	430	250	165	140	120	pF

Thermal Characteristics

	Symbol	1N5415 3SF05	1N5416 3SF1	1N5417 3SF2	1N5418 3SF4	1N5419 3SF5	1N5420 3SF6	Units
Thermal Resistance-Junction to Lead Lead length = 0.375" Lead length = 0.0"	$R_{\theta JL}$ $R_{\theta JL}$	20 4						$^\circ\text{C/W}$
Thermal Resistance-Junction to Ambient on 0.06" thick pcb. 1 oz. copper	$R_{\theta JA}$	75						$^\circ\text{C/W}$

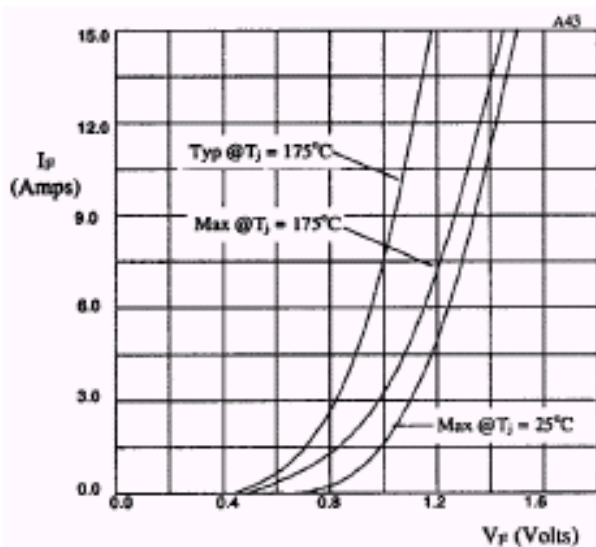
POWER DISCRETES
Typical Characteristics


Fig 1. Forward voltage drop as a function of forward current.

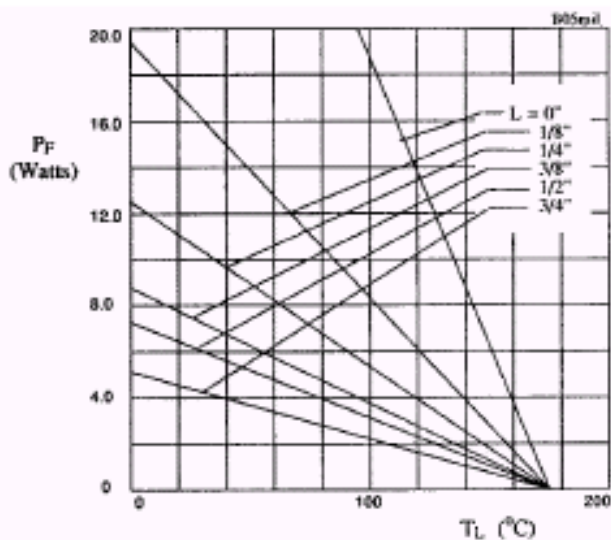


Fig 2. Maximum power versus lead temperature.

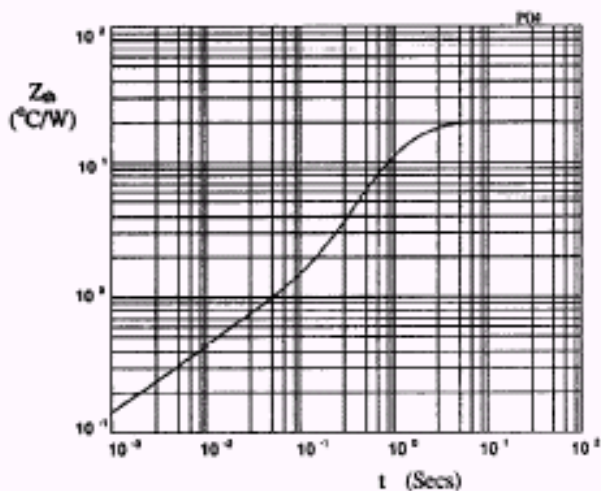


Fig 3. Transient thermal impedance characteristic.

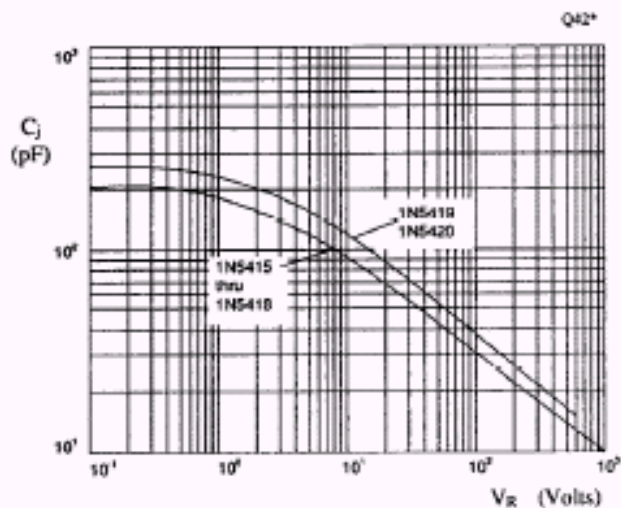


Fig 4. Typical junction capacitance as a function of reverse voltage.

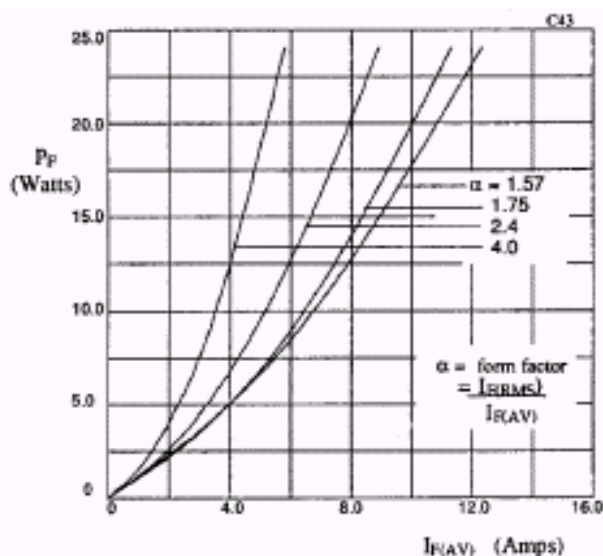
POWER DISCRETES
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Fig 5. Forward power dissipation as a function of forward current, for sinusoidal operation.

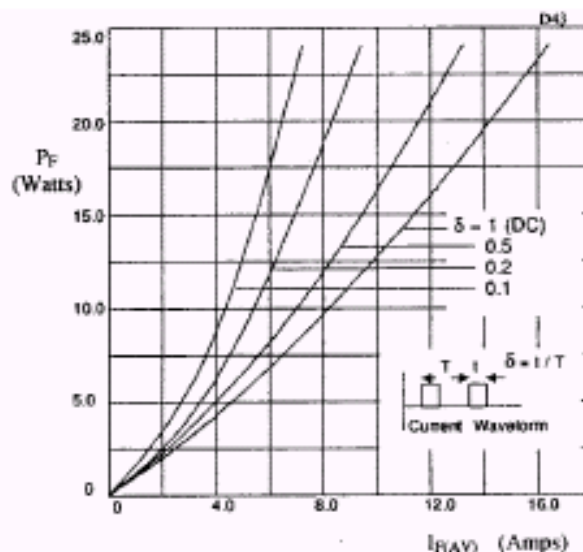


Fig 6. Forward power dissipation as a function of forward current, for square wave operation.

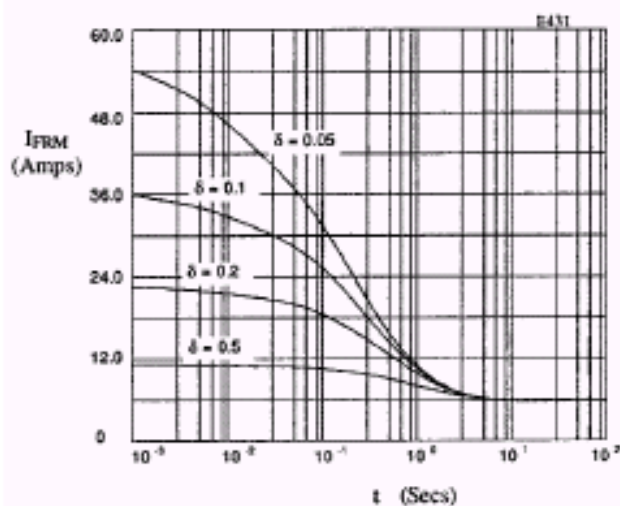


Fig 7. Typical repetitive forward current as a function of pulse width at 55°C; $R_{\theta JL} = 20^\circ\text{C/W}$; V_{RWM} during $1 - \delta$.

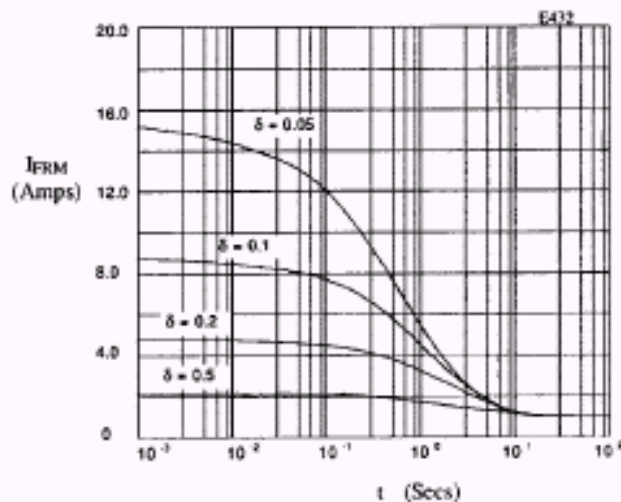


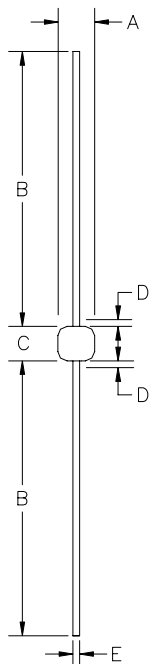
Fig 8. Typical repetitive forward current as a function of pulse width at 100°C; $R_{\theta JL} = 80^\circ\text{C/W}$; V_{RWM} during $1 - \delta$.

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Ordering Information

Part Number	Description
1N5415 1N5416 1N5417 1N5418 1N5419 1N5420 3SF05 3SF1 3SF2 3SF4 3SF5 3SF6	Axial leaded hermetically sealed ⁽¹⁾

Note:

(1) Available in bulk and tape and reel packaging. Please consult factory for quantities.

Outline Drawing


G4

Dimensions					
DIM ^N	Inches		Millimeters		Note
	MIN	MAX	MIN	MAX	
A	0.135	0.18	3.43	4.57	-
B	0.9	1.3	22.9	33.0	-
C	0.13	0.17	3.3	4.32	-
D	-	0.05	-	1.27	1
E	0.037	0.042	0.94	1.07	-

Note:

(1) Lead diameter uncontrolled over this region.

Weight = 0.04oz

Contact Information

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